Active-Semi

ACT4060

ACT4060   WIDE INPUT 2A STEP DOWN CONVERTER

FEATURES

- **2A Output Current**
- **Up to 95% Efficiency**
- **4.75V to 20V Input Range**
- **8µA Shutdown Supply Current**
- **410kHz Switching Frequency**
- **Adjustable Output Voltage**
- **Cycle-by-Cycle Current Limit Protection**
- **Thermal Shutdown Protection**
- **Frequency Fold Back at Short Circuit**
- **Stability with Wide Range of Capacitors, Including Low ESR Ceramic Capacitors**
- **SOP-8 Package**

APPLICATIONS

- **TFT LCD Monitors**
- **Portable DVDs**
- **Car-Powered or Battery-Powered Equipments**
- **Set-Top Boxes**
- **Telecom Power Supplies**
- **DSL and Cable Modems and Routers**
- **Termination Supplies**

GENERAL DESCRIPTION

The ACT4060 is a current-mode step-down DC-DC converter that generates up to 2A output current at 410kHz switching frequency. The device utilizes Active-Semi's proprietary ISOBCD20 process for operation with input voltage up to 20V.

Consuming only 8µA in shutdown mode, the ACT4060 is highly efficient with peak efficiency at 95% when in operation. Protection features include cycle-by-cycle current limit, thermal shutdown, and frequency fold back at short circuit.

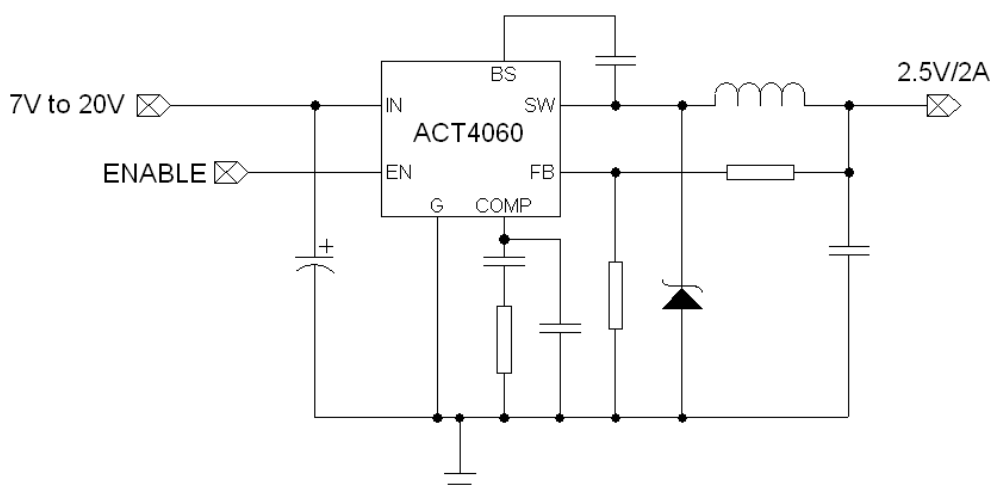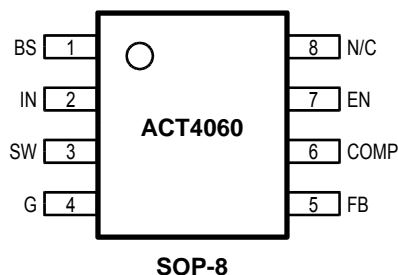The ACT4060 is available in SOP-8 package and requires very few external devices for operation.

Figure 1. Typical Application Circuit

ORDERING INFORMATION

PART NUMBER	TEMPERATURE RANGE	PACKAGE	PINS
ACT4060SH	-40°C to 85°C	SOP-8	8

PIN CONFIGURATION

```
        BS  ┌ 1        ○        8 ┐  N/C
        IN  ┌ 2                 7 ┐  EN
                    ACT4060
        SW  ┌ 3                 6 ┐  COMP
        G   ┌ 4                 5 ┐  FB
```

SOP-8

PIN DESCRIPTION

PIN NUMBER	PIN NAME	PIN DESCRIPTION
1	BS	Bootstrap. This pin acts as the positive rail for the high-side switch's gate driver. Connect a 10nF between this pin and SW.
2	IN	Input Supply. Bypass this pin to G with a low ESR capacitor. See *Input Capacitor* in *Application Information* section.
3	SW	Switch Output. Connect this pin to the switching end of the inductor.
4	G	Ground.
5	FB	Feedback Input. The voltage at this pin is regulated to 1.293V. Connect to the resistor divider between output and ground to set output voltage.
6	COMP	Compensation Pin. See *Compensation Technique* in *Application Information* section.
7	EN	Enable Input. When higher than 1.3V, this pin turns the IC on. When lower than 0.7V, this pin turns the IC off. Output voltage is discharged when the IC is off. This pin has a small internal pull up current to a high level voltage when pin is not connected.
8	N/C	Not Connected.

ABSOLUTE MAXIMUM RATINGS

(Note: Do not exceed these limits to prevent damage to the device. Exposure to absolute maximum rating conditions for long periods may affect device reliability.)

PARAMETER	VALUE	UNIT
IN Supply Voltage	-0.3 to 25	V
SW Voltage	-1 to V_{IN} + 1	V
BS Voltage	V_{SW} – 0.3 to V_{SW} + 8	V
EN, FB, COMP Voltage	-0.3 to 6	V
Continuous SW Current	Internally limited	A
Junction to Ambient Thermal Resistance (θ_{JA})	105	°C/W
Maximum Power Dissipation	0.76	W
Operating Junction Temperature	-40 to 150	°C
Storage Temperature	-55 to 150	°C
Lead Temperature (Soldering, 10 sec)	300	°C

ELECTRICAL CHARACTERISTICS

(V_{IN} = 12V, T_A = 25°C unless otherwise specified)

| PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage	V_{IN}	Vout = 5V, I_{LOAD} = 0A to 1A	7		20	V
Feedback Voltage	V_{FB}	4.75V ≤ V_{IN} ≤ 20V, V_{COMP} = 1.5V	1.267	1.293	1.319	V
High-Side Switch On Resistance	R_{ONH}			0.20		Ω
Low-Side Switch On Resistance	R_{ONL}			4.7		Ω
SW Leakage		V_{EN} = 0		0	10	µA
Current Limit	I_{LIM}		2.4	2.85		A
COMP to Current Limit Transconductance	G_{COMP}			1.8		A/V
Error Amplifier Transconductance	G_{EA}	ΔI_{COMP} = ±10µA		550		µA/V
Error Amplifier DC Gain	A_{VEA}			4000		V/V
Switching Frequency	f_{SW}		350	410	470	kHz
Short Circuit Switching Frequency		V_{FB} = 0		50		kHz
Maximum Duty Cycle	D_{MAX}	V_{FB} = 1.1V		90		%
Minimum Duty Cycle		V_{FB} = 1.4V			0	%
Enable Threshold Voltage		Hysteresis = 0.1V	0.7	1	1.3	V
Enable Pull Up Current		Pin pulled up to 4.5V typically when left unconnected		2		µA
Supply Current in Shutdown		V_{EN} = 0		8	20	µA
IC Supply Current in Operation		V_{EN} = 3V, V_{FB} = 1.4V		0.7		mA
Thermal Shutdown Temperature		Hysteresis = 10°C		160		°C
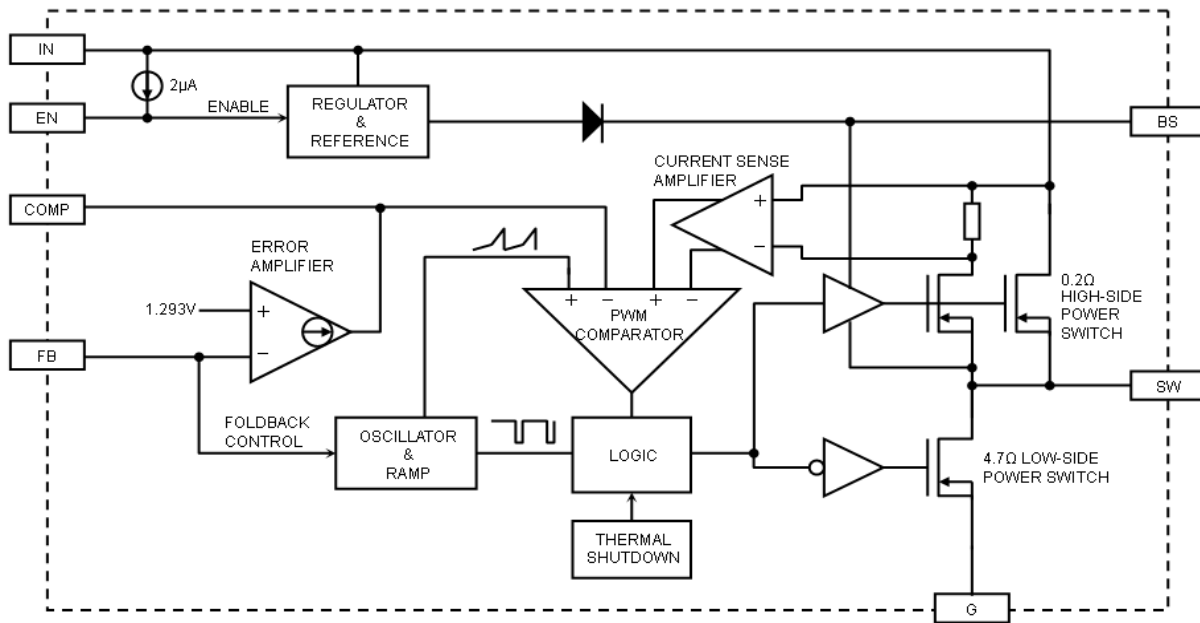
Figure 2. Functional Block Diagram

FUNCTIONAL DESCRIPTION

As seen in Figure 2, *Functional Block Diagram*, the ACT4060 is a current mode pulse width modulation (PWM) converter. The converter operates as follows:

A switching cycle starts when the rising edge of the Oscillator clock output causes the High-Side Power Switch to turn on and the Low-Side Power Switch to turn off. With the SW side of the inductor now connected to IN, the inductor current ramps up to store energy in the its magnetic field. The inductor current level is measured by the Current Sense Amplifier and added to the Oscillator ramp signal. If the resulting summation is higher than the COMP voltage, the output of the PWM Comparator goes high. When this happens or when Oscillator clock output goes low, the High-Side Power Switch turns off and the Low-Side Power Switch turns on. At this point, the SW side of the inductor swings to a diode voltage below ground, causing the inductor current to decrease and magnetic energy to be transferred to output. This state continues until the cycle starts again.

The High-Side Power Switch is driven by logic using BS bootstrap pin as the positive rail. This pin is charged to V_{SW} + 6V when the Low-Side Power Switch turns on.

The COMP voltage is the integration of the error between FB input and the internal 1.293V reference. If FB is lower than the reference voltage, COMP tends to go higher to increase current to the output. Current limit happens when COMP reaches its maximum clamp value of 2.55V.

The Oscillator normally switches at 410kHz. However, if FB voltage is less than 0.7V, then the switching frequency decreases until it reaches a minimum of 50kHz at V_{FB} = 0.5V.

SHUTDOWN CONTROL

The ACT4060 has an enable input EN for turning the IC on or off. When EN is less than 0.7V, the IC is in 8µA low current shutdown mode and output is discharged through the Low-Side Power Switch. When EN is higher than 1.3V, the IC is in normal operation mode. EN is internally pulled up with a 2µA current source and can be left unconnected for always-on operation. Note that EN is a low voltage input with a maximum voltage of 6V; it should never be directly connected to IN.

THERMAL SHUTDOWN

The ACT4060 automatically turns off when its junction temperature exceeds 160°C.

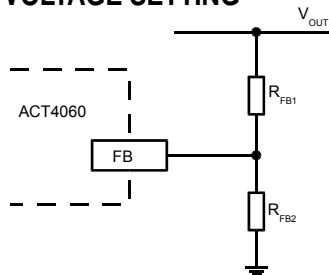# APPLICATION INFORMATION

OUTPUT VOLTAGE SETTING

Figure 3. Output Voltage Setting

Figure 3 shows the connections for setting the output voltage. Select the proper ratio of the two feedback resistors R_{FB1} and R_{FB2} based on the output voltage. Typically, use $R_{FB2} \approx 10k\Omega$ and determine R_{FB1} from the output voltage:

$$R_{FB1} = R_{FB2} \left(\frac{V_{OUT}}{1.293V} - 1 \right) \qquad (1)$$

INDUCTOR SELECTION

The inductor maintains a continuous current to the output load. This inductor current has a ripple that is dependent on the inductance value: higher inductance reduces the peak-to-peak ripple current. The trade off for high inductance value is the increase in inductor core size and series resistance, and the reduction in current handling capability. In general, select an inductance value L based on ripple current requirement:

$$L = \frac{V_{OUT} \bullet (V_{IN} - V_{OUT})}{V_{IN} f_{SW} I_{OUTMAX} K_{RIPPLE}} \qquad (2)$$

where V_{IN} is the input voltage, V_{OUT} is the output voltage, f_{SW} is the switching frequency, I_{OUTMAX} is the maximum output current, and K_{RIPPLE} is the ripple factor. Typically, choose K_{RIPPLE} = 30% to correspond to the peak-to-peak ripple current being 30% of the maximum output current.

With this inductor value (Table 1), the peak inductor current is $I_{OUT} \bullet (1 + K_{RIPPLE} / 2)$. Make sure that this peak inductor current is less that the 3A current limit. Finally, select the inductor core size so that it does not saturate at 3A.

Table 1. Typical Inductor Values

V_{OUT}	1.5V	1.8V	2.5V	3.3V	5V
L	6.8µH	6.8µH	10µH	15µH	22µH

INPUT CAPACITOR

The input capacitor needs to be carefully selected to maintain sufficiently low ripple at the supply input of the converter. A low ESR capacitor is highly recommended. Since large current flows in and out of this capacitor during switching, its ESR also affects efficiency.

The input capacitance needs to be higher than 10µF. The best choice is the ceramic type; however, low ESR tantalum or electrolytic types may also be used provided that the RMS ripple current rating is higher than 50% of the output current. The input capacitor should be placed close to the IN and G pins of the IC, with shortest traces possible. In the case of tantalum or electrolytic types, they can be further away if a small parallel 0.1µF ceramic capacitor is placed right next to the IC.

OUTPUT CAPACITOR

The output capacitor also needs to have low ESR to keep low output voltage ripple. The output ripple voltage is:

$$V_{RIPPLE} = I_{OUTMAX} K_{RIPPLE} R_{ESR}$$
$$+ \frac{V_{IN}}{28 \bullet f_{SW}^2 L C_{OUT}} \qquad (3)$$

where I_{OUTMAX} is the maximum output current, K_{RIPPLE} is the ripple factor, R_{ESR} is the ESR resistance of the output capacitor, f_{SW} is the switching frequency, L in the inductor value, C_{OUT} is the output capacitance. In the case of ceramic output capacitors, R_{ESR} is very small and does not contribute to the ripple. Therefore, a lower capacitance value can be used for ceramic type. In the case of tantalum or electrolytic type, the ripple is dominated by R_{ESR} multiplied by the ripple current. In that case, the output capacitor is chosen to have sufficiently low ESR.

For ceramic output type, typically choose a capacitance of about 22µF. For tantalum or electrolytic type, choose a capacitor with less than 50mΩ ESR.

RECTIFIER DIODE

Use a Schottky diode as the rectifier to conduct current when the High-Side Power Switch is off. The Schottky diode must have current rating higher than the maximum output current and the reverse voltage rating higher than the maximum input voltage.

STABILITY COMPENSATION

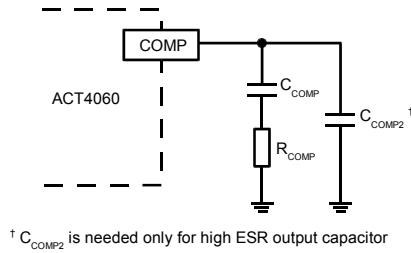† C_{COMP2} is needed only for high ESR output capacitor

Figure 4. Stability Compensation

The feedback system of the IC is stabilized by the components at COMP pin, as shown in Figure 4. The DC loop gain of the system is determined by the following equation:

$$A_{VDC} = \frac{1.3V}{I_{OUT}} A_{VEA} G_{COMP} \qquad (4)$$

The dominant pole P1 is due to C_{COMP}:

$$f_{P1} = \frac{G_{EA}}{2\pi A_{VEA} C_{COMP}} \qquad (5)$$

The second pole P2 is the output pole:

$$f_{P2} = \frac{I_{OUT}}{2\pi V_{OUT} C_{OUT}} \qquad (6)$$

The first zero Z1 is due to R_{COMP} and C_{COMP}:

$$f_{Z1} = \frac{1}{2\pi R_{COMP} C_{COMP}} \qquad (7)$$

And finally, the third pole is due to R_{COMP} and C_{COMP2} (if C_{COMP2} is used):

$$f_{P3} = \frac{1}{2\pi R_{COMP} C_{COMP2}} \qquad (8)$$

Follow the following steps to compensate the IC:

STEP 1. Set the cross over frequency at 1/10 of the switching frequency via R_{COMP}:

$$R_{COMP} = \frac{2\pi V_{OUT} C_{OUT} f_{SW}}{10 G_{EA} G_{COMP} \bullet 1.3V}$$

$$= 1.7 \times 10^8 V_{OUT} C_{OUT} \qquad (\Omega) \qquad (9)$$

but limit R_{COMP} to 15kΩ maximum.

STEP 2. Set the zero f_{Z1} at 1/4 of the cross over frequency. If R_{COMP} is less than 15kΩ, the equation for C_{COMP} is:

$$C_{COMP} = \frac{1.8 \times 10^{-5}}{R_{COMP}} \qquad (F) \qquad (10)$$

If R_{COMP} is limited to 15kΩ, then the actual cross over frequency is 3.4 / ($V_{OUT} C_{OUT}$). Therefore:

$$C_{COMP} = 1.2 \times 10^{-5} V_{OUT} C_{OUT} \qquad (F) \qquad (11)$$

STEP 3. If the output capacitor's ESR is high enough to cause a zero at lower than 4 times the cross over frequency, an additional compensation capacitor C_{COMP2} is required. The condition for using C_{COMP2} is:

$$R_{ESRCOUT}$$

$$\geq Min\left(\frac{1.1 \times 10^{-6}}{C_{OUT}}, 0.012 \bullet V_{OUT}\right) \qquad (\Omega) \qquad (12)$$

And the proper value for C_{COMP2} is:

$$C_{COMP2} = \frac{C_{OUT} R_{ESRCOUT}}{R_{COMP}} \qquad (13)$$

Though C_{COMP2} is unnecessary when the output capacitor has sufficiently low ESR, a small value C_{COMP2} such as 100pF may improve stability against PCB layout parasitic effects.

Table 2 shows some calculated results based on the compensation method above.

Table 2. Typical Compensation for Different Output Voltages and Output Capacitors

V_{OUT}	C_{OUT}	R_{COMP}	C_{COMP}	C_{COMP2}
2.5V	22µF Ceramic	8.2kΩ	2.2nF	None
3.3V	22µF Ceramic	12kΩ	1.5nF	None
5V	22µF Ceramic	15kΩ	1.5nF	None
2.5V	47µF SP Cap	15kΩ	1.5nF	None
3.3V	47µF SP Cap	15kΩ	1.8nF	None
5V	47µF SP Cap	15kΩ	2.7nF	None
2.5V	470µF/6.3V/30mΩ	15kΩ	15nF	1nF
3.3V	470µF/6.3V/30mΩ	15kΩ	22nF	1nF
5V	470µF/10V/30mΩ	15kΩ	27nF	None

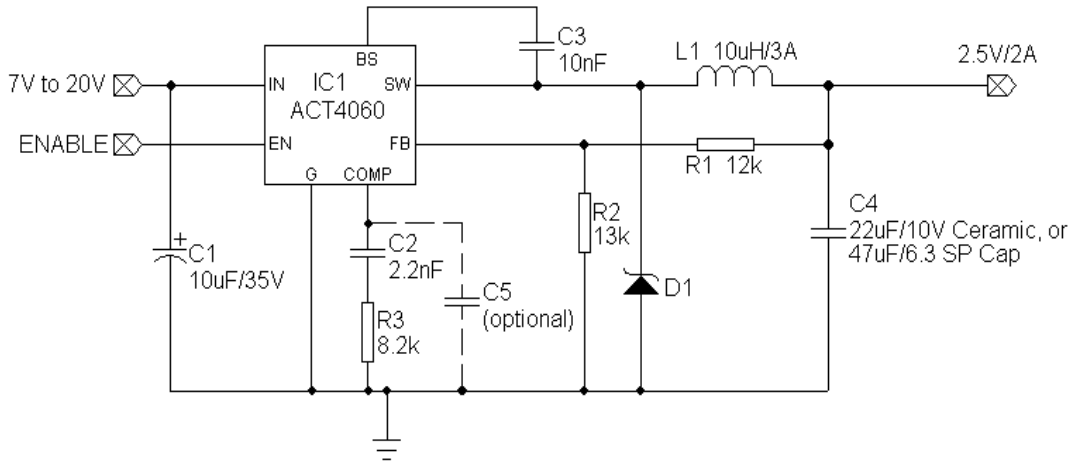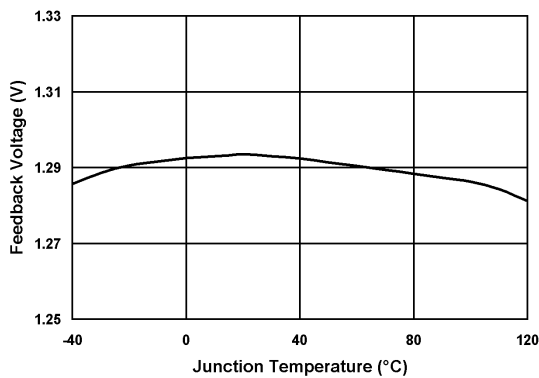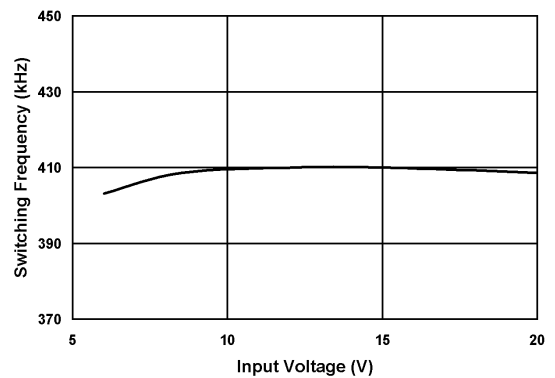Figure 5 shows a sample ACT4060 application circuit generating 2.5V/2A output.

Figure 5. ACT4060 2.5V/2A Output Application
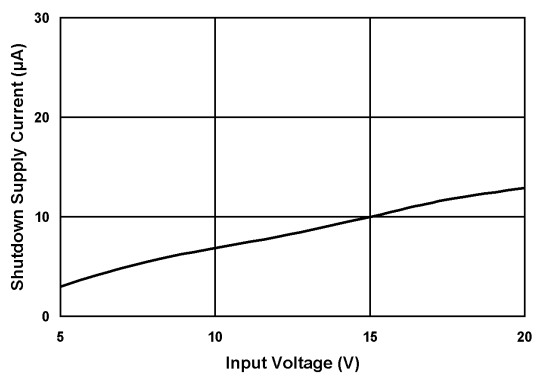
TYPICAL PERFORMANCE CHARACTERISTICS

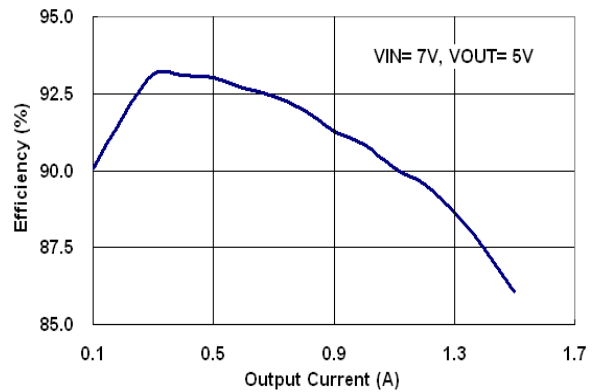**Feedback Voltage vs. Junction Temperature**

Switching Frequency vs. Input Voltage

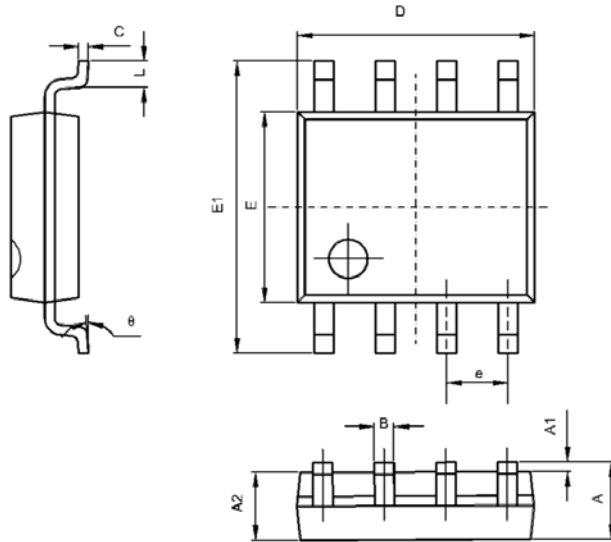**Shutdown Supply Current vs. Input Voltage**

Efficiency vs. Output Current

PACKAGE OUTLINE

SOP-8 PACKAGE OUTLINE AND DIMENSIONS

SYMBOL	DIMENSION IN MILIMETERS		DIMENSION IN INCHES	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
B	0.330	0.510	0.013	0.020
C	0.190	0.250	0.007	0.010
D	4.780	5.000	0.188	0.197
E	3.800	4.000	0.150	0.157
E1	5.800	6.300	0.228	0.248
e	1.270 TYP		0.050 TYP	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

射 频 和 天 线 设 计 培 训 课 程 推 荐

易迪拓培训(www.edatop.com)由数名来自于研发第一线的资深工程师发起成立，致力并专注于微波、射频、天线设计研发人才的培养；我们于 2006 年整合合并微波 EDA 网(www.mweda.com)，现已发展成为国内最大的微波射频和天线设计人才培养基地，成功推出多套微波射频以及天线设计经典培训课程和 ADS、HFSS 等专业软件使用培训课程，广受客户好评；并先后与人民邮电出版社、电子工业出版社合作出版了多本专业图书，帮助数万名工程师提升了专业技术能力。客户遍布中兴通讯、研通高频、埃威航电、国人通信等多家国内知名公司，以及台湾工业技术研究院、永业科技、全一电子等多家台湾地区企业。

易迪拓培训推荐课程列表： http://www.edatop.com/peixun/tuijian/

射频工程师养成培训课程套装

该套装精选了射频专业基础培训课程、射频仿真设计培训课程和射频电路测量培训课程三个类别共 30 门视频培训课程和 3 本图书教材；旨在引领学员全面学习一个射频工程师需要熟悉、理解和掌握的专业知识和研发设计能力。通过套装的学习，能够让学员完全达到和胜任一个合格的射频工程师的要求…

课程网址：http://www.edatop.com/peixun/rfe/110.html

手机天线设计培训视频课程

该套课程全面讲授了当前手机天线相关设计技术，内容涵盖了早期的外置螺旋手机天线设计，最常用的几种手机内置天线类型——如 monopole 天线、PIFA 天线、Loop 天线和 FICA 天线的设计，以及当前高端智能手机中较常用的金属边框和全金属外壳手机天线的设计；通过该套课程的学习，可以帮助您快速、全面、系统地学习、了解和掌握各种类型的手机天线设计，以及天线及其匹配电路的设计和调试…

课程网址： http://www.edatop.com/peixun/antenna/133.html

WiFi 和蓝牙天线设计培训课程

该套课程是李明洋老师应邀给惠普 (HP)公司工程师讲授的 3 天员工内训课程录像，课程内容是李明洋老师十多年工作经验积累和总结，主要讲解了 WiFi 天线设计、HFSS 天线设计软件的使用、匹配电路设计调试、矢量网络分析仪的使用操作、WiFi 射频电路和 PCB Layout 知识，以及 EMC 问题的分析解决思路等内容。对于正在从事射频设计和天线设计领域工作的您，绝对值得拥有和学习！…

课程网址：http://www.edatop.com/peixun/antenna/134.html

CST 学习培训课程套装

该培训套装由易迪拓培训联合微波 EDA 网共同推出，是最全面、系统、专业的 CST 微波工作室培训课程套装，所有课程都由经验丰富的专家授课，视频教学，可以帮助您从零开始，全面系统地学习 CST 微波工作的各项功能及其在微波射频、天线设计等领域的设计应用。且购买该套装，还可超值赠送 3 个月免费学习答疑…

课程网址：http://www.edatop.com/peixun/cst/24.html

HFSS 学习培训课程套装

该套课程套装包含了本站全部 HFSS 培训课程，是迄今国内最全面、最专业的 HFSS 培训教程套装，可以帮助您从零开始，全面深入学习 HFSS 的各项功能和在多个方面的工程应用。购买套装，更可超值赠送 3 个月免费学习答疑，随时解答您学习过程中遇到的棘手问题，让您的 HFSS 学习更加轻松顺畅…

课程网址：http://www.edatop.com/peixun/hfss/11.html

ADS 学习培训课程套装

该套装是迄今国内最全面、最权威的 ADS 培训教程，共包含 10 门 ADS 学习培训课程。课程是由具有多年 ADS 使用经验的微波射频与通信系统设计领域资深专家讲解，并多结合设计实例，由浅入深、详细而又全面地讲解了 ADS 在微波射频电路设计、通信系统设计和电磁仿真设计方面的内容。能让您在最短的时间内学会使用 ADS，迅速提升个人技术能力，把 ADS 真正应用到实际研发工作中去，成为 ADS 设计专家...

课程网址： http://www.edatop.com/peixun/ads/13.html

我们的课程优势：

※ 成立于 2004 年，10 多年丰富的行业经验，

※ 一直致力并专注于微波射频和天线设计工程师的培养，更了解该行业对人才的要求

※ 经验丰富的一线资深工程师讲授，结合实际工程案例，直观、实用、易学

联系我们：

※ 易迪拓培训官网：http://www.edatop.com

※ 微波 EDA 网：http://www.mweda.com

※ 官方淘宝店：http://shop36920890.taobao.com